

What are optoelectronic materials used for?

Optoelectronic materials are foundational for many technologies that broadly define the information age. They find applications in thin-film transistors, light emitting diodes, solar cells, sensors, and the quantum-information systems of the future.

How does optoelectronic memory work?

Here, we firstly propose an optoelectronic memory based on a new photosensitive dielectric (PSD) architecture. Data writing and erasing are realized by using an optical pulse to switch on the PSD. The unique design enables the memory to work with a programming voltage and optical power density as low as 4 V and 160  $\mu\text{W cm}^{-2}$ , respectively.

Is optical data storage a viable alternative to modern technology?

Optical data storage -- which is enabled by the use of microscopy technologies -- is a highly promising alternative to contemporary approaches because it has proven to be superior in terms of performance and durability. However, it will be necessary to increase the capacity of currently available devices.

What are the shortcomings of optoelectronic memory?

Although tens of states have been reported in literature, there are still three obvious deficiencies in most of the optoelectronic memories: large programming voltage ( $>20$  V), high optical power density ( $>1 \text{ mW cm}^{-2}$ ), and poor compatibility originating from the over-reliance on channel materials.

What is the future of optical data storage?

Because it uses bit-by-bit writing and reading, far-field super-resolution optical data storage will enable format compatibility with currently available systems. A particularly interesting perspective for the future of optical data storage relies on the development of nanocomposites based on RNCs in combination with graphene or graphene oxide.

What is a new optoelectronic memory structure with a photosensitive dielectric (PSD)?

A new optoelectronic memory structure with a photosensitive dielectric (PSD) is designed on the basis of the flash memory cell. As shown in Fig. 1c, the original normal dielectric (ND) layer in the flash memory (Fig. 1a) is replaced with a PSD layer, and the TD layer between the FG and the channel is replaced with an ND layer.

2.1 Graphene. Graphene, the first member of 2D family, offers several advantages compared with other 2D materials due to its Dirac-core-like gapless energy structure where the valence band ...

optoelectronic devices and second in energy harvesting and energy storage devices where it finds its use as an electron transport layer (ETL) and an electrode material, ...

After that, the up-to-date optoelectronic information devices based on 2D materials, including ultrafast lasers, light emitters, frequency convertors, modulators, detectors, plasmonic generators, and sensors, are reviewed.

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1 ??&#0183; Energy conservation is necessary due to the rising energy demand, for economic benefits, and to decrease global warming. 1 Energy storage devices can store that converted ...

[39-41] Among these devices, photodetectors convert light into electrical signals, optoelectronic memories allow for the storage and retrieval of large amounts of visual information, while optical synaptic devices mimic the ...

Light-energy conversion materials Light storage with an optical display Photoelectric engineering Biomedical photonics (2) Photoelectric information Photoelectronics and technology ...

Tin oxide for optoelectronic, photovoltaic and energy storage devices: a review. Goutam Kumar Dalapati \* abcde, Himani Sharma f, Asim Guchhait g, Nilanjan Chakrabarty h, Priyanka ...

5 ???&#0183; In the current investigation, we have implemented first-principles calculations to examine the structural, elastic, electrical, and optical characteristics of LiBH<sub>2</sub>. All of the ...

While optoelectronic systems are the backbone of solar energy conversion, electrochemical energy storage relies on the transfer of ions. Bridging the gap between the two, enabled by optoionics, is bound to evolve new ...

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Synthesis and electrochemical characterization of pseudocapacitive ?-MoO<sub>3</sub> thin film as transparent electrode material in optoelectronic and energy storage devices Author ...

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Tin oxide for optoelectronic, photovoltaic and energy storage devices: a review. Priyanka Bamola. ... A novel synthesis of tin oxide thin films by the sol-gel process for optoelectronic ...

In this study, the physical properties of the perovskite hydrides  $\text{CsXH}_3$  ( $\text{X} = \text{Ca, Sr and Ba}$ ) were explored using density functional theory (DFT) to assess their suitability for optoelectronic and ...

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